## Synthesis, Crystal Structure, and Electron-Accepting Property of the BF<sub>2</sub> Complex of a Dihydroxydione with a Perfluorotetracene Skeleton

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## **ABSTRACT**

A BF $_2$  complex containing an octafluorotetracene moiety was synthesized as a new type of electron acceptor. This compound exhibits a long-wavelength absorption based on the perfluorotetracene skeleton and high electron affinity due to its quadrupolar structure enhanced by fluorination. In the crystal, the molecules are arranged with short F··· $\pi$  and F···F contacts affording a dense crystal packing. The BF $_2$  complex exhibited n-type semiconducting behavior.

Polycyclic aromatic compounds have attracted considerable attention since they are promising materials for active layers of organic field-effect transistors (OFETs). Acene compounds such as pentacene and rubrene exhibit good p-type semiconducting properties. These compounds have extended  $\pi$ -conjugation and rigid planality, thereby resulting in suitable intermolecular  $\pi$ - $\pi$  overlap and face-to-edge interactions in the solid state. On the other hand, n-type semiconductors

with high electron affinities have been prepared by introduction of fluorine and trifluoromethyl groups into arene moieties as found in the synthesis of perfluoropentacene,<sup>3</sup> hexafluorohexa-*peri*-hexabenzocoronene<sup>4</sup> and 2,6-bis(4-trifluoro-

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methylphenyl)anthracene.<sup>5</sup> Tetracarboxylic diimides with naphthalene,<sup>6</sup> anthracene,<sup>7</sup> and perylene<sup>8</sup> skeletons were also found to be good n-type semiconductors with high electron mobilities. Furthermore, electron-deficient heteropolycyclic compounds<sup>9</sup> and quinone derivatives<sup>10</sup> have been studied as potential electron-transporting materials. We recently synthesized BF<sub>2</sub> complexes of dihydroxydione of tetracene and perylene as a new type of electron-deficient arene compound.<sup>11</sup> The BF<sub>2</sub> chelation enhances the electron-withdrawing property as well as the  $\pi$ -electron delocalization of the tetracene and perylene moieties. Thus, these compounds showed long-wavelength absorptions and high electron affinity. The BF<sub>2</sub> complex with a tetracene skeleton (DHND-BF<sub>2</sub>) exhibited n-type semiconducting behavior, although the electron mobility was not so high  $(1.5 \times 10^{-5})$ cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>). For improvement of its electron mobility, we undertook fluorination to DHND-BF2 to yield a new electron acceptor F-DHND-BF<sub>2</sub> (Scheme 1). This com-

Scheme 1. Structure of BF<sub>2</sub> Complexes

 $X = H: DHND-BF_2$  $X = F: F-DHND-BF_2$ 

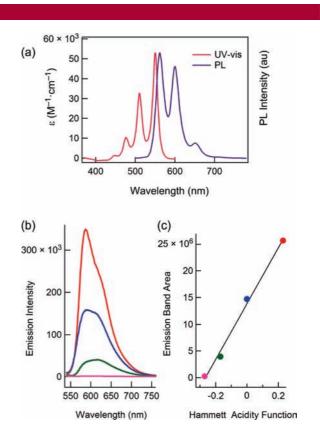
pound is characterized by its quadrupolar structure enhanced by fluorination in its resonance contributor, affording small HOMO-LUMO energy and low-lying LUMO energy. The BF<sub>2</sub> chelation and fluorination also affect morphology in the molecular packing as heteroatom contacts. In this paper, we

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report the synthesis, electron-accepting properties, and crystal structure of F-DHND-BF<sub>2</sub> and its applications in the OFET study.

The synthesis of F-DHND-BF<sub>2</sub> was performed by chelation with boron trifluoride diethyl etherate (BF<sub>3</sub>•OEt<sub>2</sub>) to 1,2,3,4,7,8,9,10-octafluoro-6,11-dihydroxy-5,12-naphthacenedione (F-DHND), which was prepared with a synthetic method developed by Suzuki et al.12 F-DHND-BF<sub>2</sub> was obtained as red crystals with a yield of 55% after sublimation at 275 °C under 10<sup>-3</sup> Torr. This compound was stable in air in the solid state. However, it was more unstable in solution than DHND-BF2 due to the ready hydrolysis. The thermogravimetric analysis (TGA) indicated a good thermal stability of F-DHND-BF<sub>2</sub>. The 5% weight loss was observed at 277 °C, and this temperature is lower than that of DHND-BF<sub>2</sub> (325 °C). The weight loss is attributable to sublimation because a differential scanning calorimetry (DSC) analysis exhibited broad endothermic peaks in the region of 250-380 °C (Figure S9, Supporting Information).

The absorption and photoluminescence (PL) spectra of F-DHND-BF<sub>2</sub> in dichloromethane are shown in Figure 1a, and their spectroscopic properties are listed in Table 1. The absorption bands in the region of 430-580 nm are attributed to the tetracene moiety. These maxima are red-shifted as compared to those of DHND-BF<sub>2</sub>. These red-shifts are due



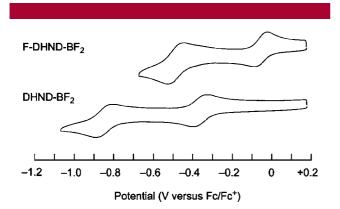
**Figure 1.** Spectroscopic properties of F–DHND–BF<sub>2</sub>: (a) UV–vis and PL spectra in  $CH_2Cl_2$ , (b) PL spectra (concd  $2.0 \times 10^{-5}$  M) in aromatic solvents (red line, chlorobenzene; blue line, benzene; green line, toluene; pink line, anisole), and (c) relationship of emission band areas with Hammett acidity functions.

**Table 1.** Spectroscopic Properties of DHND Derivatives<sup>a</sup>

compound	$\lambda_{abs} \ (nm)$	$\lambda_{PL}\left(nm\right)$	$\lambda_{edge} \ (eV)$		
$F-DHND-BF_2$	550, 510, 476	562, 600, 651	2.13		
$\mathrm{DHND}\mathrm{-BF}_2$	523, 487, 455	529, 567, 615	$2.23^b$		
F-DHND	546, 508, 477	558, 595, 646  sh	2.14		
<sup>a</sup> In CH <sub>2</sub> Cl <sub>2</sub> . <sup>b</sup> Reinvestigated.					

to the introduction of fluorine atoms because their maxima are close to those of F-DHND. For F-DHND-BF<sub>2</sub>, a small HOMO-LUMO energy gap of 2.13 eV was obtained from the absorption edge. The PL spectrum of F-DHND-BF<sub>2</sub> in dichloromethane exhibited a vibronic structure based on the tetracene moiety in the wavelength region of 530-680 nm. The Stokes shift is small (12 nm), indicating that F-DHND-BF<sub>2</sub> has a rigid geometry similar to that of DHND-BF<sub>2</sub> (6 nm). On the other hand, the PL spectrum of F-DHND-BF<sub>2</sub> in toluene is broad. The maximum ( $\lambda_{\text{max}}$  615 nm) is red-shifted as compared to the shortest-wavelength maximum in dichloromethane. Figure 1b shows the PL spectra in various aromatic solvents in the concentration of  $2.0 \times 10^{-5}$  M. When the solvent with stronger electrondonating ability is used, the PL intensity decreases, where a linear relationship between their emission band areas and Hammett acidity functions of solvents is observed, as shown in Figure 1c. This quenching can be rationalized in terms of photoinduced charge-transfer interactions F-DHND-BF<sub>2</sub> and electron-donating solvents, indicating the high electron affinity of F-DHND-BF<sub>2</sub>.

To investigate the electron affinity of  $F-DHND-BF_2$ , the cyclic voltammetry (CV) measurement was performed in acetonitrile with 0.1 M  $n\text{-Bu}_4N\text{ClO}_4$ . The voltammogram displays two reversible reduction waves, as shown in Figure 2. The half-wave reduction potentials of  $F-DHND-BF_2$  are

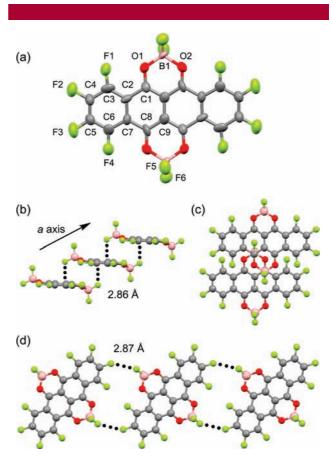


**Figure 2.** Cyclic voltammograms of BF<sub>2</sub> complexes.

observed at -0.06 and -0.50 V versus Fc/Fc<sup>+</sup>. These values are more positive than those of DHND-BF<sub>2</sub> ( $E_{1/2}^{\text{red}}$ : -0.37

and -0.85 V), indicating an increase of electron affinity by fluorination to the DHND skeleton. These reduction potentials are more positive than those of F–DHND ( $E_p^{\rm red}$ : -0.91 V) and perfluorotetracene (F–tetracene) ( $E^{\rm red}$ : -1.49 V). Therefore, the electron-accepting ability of F–DHND–BF $_2$  is much greater than those of F–DHND and F–tetracene. This result is attributed to the BF $_2$  chelation, which yields the quadrupolar resonance structure (Scheme 1). The difference between the first and second reduction potentials for F–DHND–BF $_2$  (0.44 V) is smaller than that for DHND–BF $_2$  (0.48 V), indicating that on-site Coulomb repulsion is slightly decreased by the fluorination.

The molecular structure of F-DHND-BF<sub>2</sub> was investigated by X-ray crystallographic analysis. Single crystals suitable for the X-ray analysis were grown by slow sublimation. In the crystal, the molecule is centrosymmetric, as shown in Figure 3a. The two boron atoms exist on the center



**Figure 3.** Crystal structure of F-DHND-BF<sub>2</sub>: (a) molecular structure (ellipsoid); (b) molecular stacking; (c) overlap mode; (d) molecular tape.

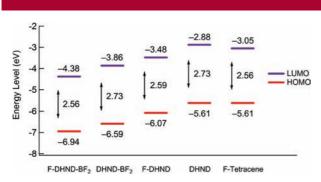
line of the molecule, and the  $B_1-O_1$  and  $B_1-O_2$  bond distances are 1.48(1) and 1.52(1) Å, respectively. The tetracene moiety is planar. The B-F bonds are asymmetrically placed on the molecular plane (Figure 3b), and the  $B_1-F_5$  and  $B_1-F_6$  bonds are 1.37(1) and 1.35(1) Å, respectively. The molecules are stacked along the a axis to form a column with short  $F^{\bullet\bullet}\pi$  contacts. The fluorine atoms

4328 Org. Lett., Vol. 11, No. 19, 2009

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are interacted with the benzene rings of the neighboring molecules with an intermolecular distance of 2.86 Å (Figure 3c). This contact distance is shorter than the sum of the van der Waals radii of fluorine and carbon atoms (3.17 Å). The molecules are arranged to form a molecular tape with short F•••F contacts, whose contact distances are 2.87 Å (Figure 3d). These heteroatom contacts lead to a dense crystal packing ( $D_x = 2.10 \text{ g cm}^{-3}$ ).

The molecular orbital (MO) calculations of F-DHND-BF<sub>2</sub> and its related compounds were performed using B3LYP/6-31G(d),<sup>13</sup> and the energy diagram of their HOMOs and LUMOs is summarized in Figure 4. Although



**Figure 4.** Energy diagram of the HOMOs and LUMOs of  $F-DHND-BF_2$  and its related compounds obtained by B3LYP/6-31G(d) calculations.

both the  $BF_2$  chelation and fluorination work for a decrease of their HOMO and LUMO energies, the  $BF_2$  chelation is more effective since the HOMO and LUMO energies of  $BF_2$  complexes are lower than those of F-tetracene. Furthermore, the small HOMO-LUMO energy gap of F-DHND- $BF_2$  is attributable to the F-tetracene skeleton, where the orbitals in the HOMO and LUMO are extended on the fluorine groups. These calculations are consistent with the CV data and UV-vis absorption spectra of F-DHND- $BF_2$  and its related compounds.

The field-effect mobilities were measured on the devices with a bottom contact configuration. The organic layers were fabricated on an SiO<sub>2</sub> dielectric layer by vacuum deposition (10<sup>-5</sup> Pa), and the OFET measurements were performed in a vacuum. The films of F-DHND-BF<sub>2</sub> exhibited n-type semiconducting behavior (Figure S12, Supporting Information), and the characteristics of OFET devices are listed in Table 2. Both the treatment of the substrate surface with hexamethyldisilazane (HMDS) and the substrate temperature are effective for increases of its electron mobility and on/

Table 2. OFET Performance of F-DHND-BF<sub>2</sub> Films

surface	substrate temp (°C)	mobility (cm²/V•s)	on/off ratio	threshold (V)
bare HMDS	rt rt.	$9.1 \times 10^{-7} \ 2.6 \times 10^{-5}$	$2 \times 10^{2}$ $3 \times 10^{4}$	+5 +17
HMDS	65	$7.8 \times 10^{-5}$	$4 \times 10^5$	+14

off ratio. According to the X-ray diffraction (XRD) analysis, the film deposited on the HMDS surface at 65 °C exhibits three diffraction peaks (*d* space values: 10.39, 5.19, and 3.47 Å), whereas the films deposited at room temperature do not show any XRD peaks (Figure S13, Supporting Information). This fact indicates that the crystallinity of films increased by annealing. The *d*-spacing of 10.39 Å suggests that the molecules stand with the BF<sub>2</sub> units on the substrate affording a layer structure. The field-effect mobilities may be attributed to this molecular aggregation. The threshold voltages observed are relatively small, indicating effective electron injection due to the high electron-accepting property of F–DHND–BF<sub>2</sub>.

In conclusion, we synthesized a BF<sub>2</sub> complex with an octafluorotetracene moiety as a new type of electron acceptor. This compound exhibited a small HOMO–LUMO energy gap and a high electron affinity, as observed from the spectral and electrochemical studies. The small HOMO–LUMO energy gap is attributable to the F–tetracene skeleton. Both the BF<sub>2</sub> chelation and fluorination are highly effective for a decrease of LUMO energy. In the crystal, the molecules are arranged to form a tapelike network with short F···π and F···F contacts, leading to a dense crystal packing. The BF<sub>2</sub> complex showed n-type semiconducting behaviors in the devices with a bottom contact configuration. Further investigation on the OFET application of F–DHND–BF<sub>2</sub> is in progress.

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**Supporting Information Available:** Synthetic procedures, additional characterization data, and X-ray crystallographic data in CIF format. This material is available free of charge via the Internet at http://pubs.acs.org.

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Org. Lett., Vol. 11, No. 19, 2009

<sup>(13)</sup> See Supporting Information for the MO calculations.